



MH205A

High Linearity Cellular-Band MMIC Mixer

The Communications Edge™

Product Information

Product Features

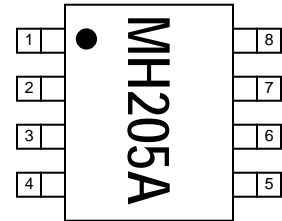
- +35 dBm Input IP3
- 7 dB Conversion Loss
- RF: 800 – 960 MHz
- LO: 700 – 890 MHz
- IF: 70 – 120 MHz
- +17 dBm Drive Level
- Lead-free / RoHS-compliant / Green SOIC-8 package
- No External Bias Required

Product Description

The MH205A is a passive GaAs MESFET mixer that provides high dynamic range performance in a low-cost lead-free/green/RoHS-compliant SOIC-8 package. WJ's MH205A uses patented techniques to realize +35 dBm Input IP3 at an LO drive level of +17 dBm and can be used for upconverting or downconverting low-side LO applications. This single monolithic integrated circuit does not require any external baluns or bias elements.

Typical applications include frequency up/down conversion, modulation and demodulation for receivers and transmitters used in 2.5G and 3G GSM/CDMA/wCDMA mobile infrastructure in the cellular frequency band.

Functional Diagram



Function	Pin No.
LO	2
IF & RF*	7
GND	1, 3, 4, 6, 8
N/C or GND	5

* External components (inductors & capacitors) are required to diplex the signal

Applications

- 2.5G and 3G GSM/CDMA/wCDMA Mobile Infrastructure

Specifications

Parameters	Units	Min	Typ	Max	Comments
RF Frequency Range	MHz		800 – 960		
LO Frequency Range	MHz		700 – 890		
IF Frequency Range	MHz		70 – 120		
SSB Conversion Loss	dB		7	9.5	See note 1
Noise Figure	dB		7.5		See note 2
Input IP3	dBm	+28	+35		See notes 1 and 3
Input P1dB	dBm		+18		
LO – RF Isolation	dB	30	37		
LO – IF Isolation	dB	47	55		
RF – IF Isolation	dB		15		
Return Loss: RF Port	dB		15		See note 4
Return Loss: IF Port	dB		16		See note 4
Return Loss: LO Port	dB		11		
LO Drive Level	dBm		+17		

1. Test conditions unless otherwise noted: RF / IF = 803 / 70 and 963 / 70 with a low-side LO at +17 dBm in a downconverting application at 25 °C. The diplexer shown on the application circuit is used in the test fixture.
2. Assumes LO injection noise is filtered at the thermal noise floor, -174 dBm/Hz, at the RF, IF, and Image frequencies.
3. IIP3 is measured with Af = 1 MHz with RFin = 0 dBm / tone.
4. The return loss is measured after the diplexer which splits the RF and IF signals from the mixer.

Absolute Maximum Rating

Parameter	Rating
Operating Case Temperature	-40 to +85 °C
Storage Temperature	-65 to +100 °C
LO Power	+21 dBm
Input IF / RF Power	+20 dBm

Operation of this device above any of these parameters may cause permanent damage.

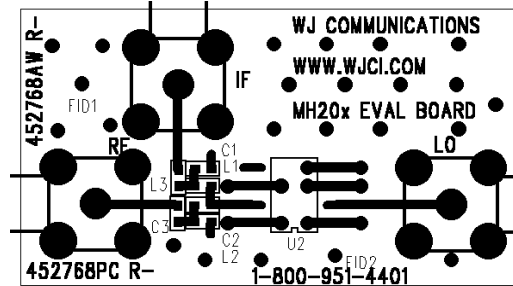
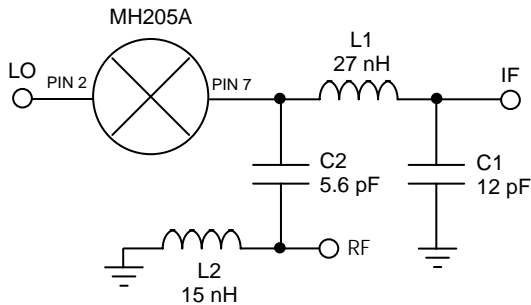
Ordering Information

Part No.	Description
MH205A-G	High Dynamic Range Cellular-band MMIC Mixer (lead-free/green/RoHS-compliant SOIC-8 package)
MH205A-PCB	Fully-Assembled Mixer Application Board

Specifications and information are subject to change without notice

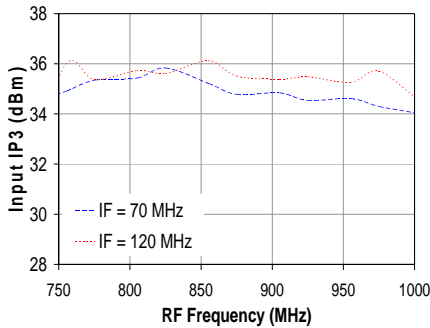


Typical Downconversion Performance Plots Performance using the circuitry on the MH205A-PCB Evaluation Board

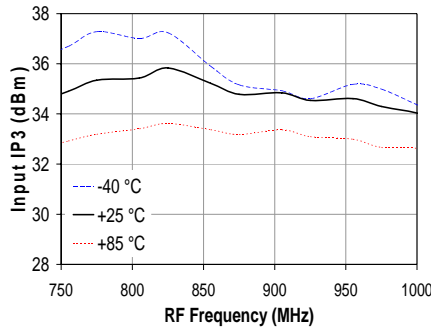


Circuit Board Material: .014" FR-4, 4 layers, .062" total thickness
All passive components are 0402 size.
All other pins on mixer are grounded.

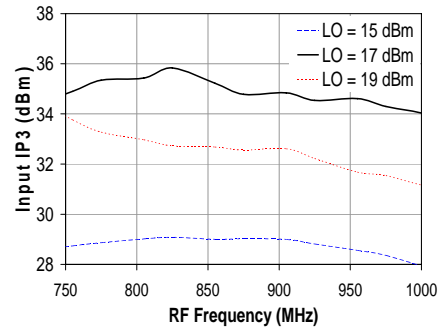
Input IP3 vs RF Frequency vs IF Frequency
Low-side Downconversion, LO = +17 dBm, 25 °C



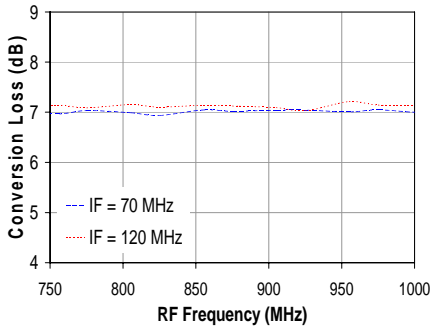
Input IP3 vs RF Frequency vs Temperature
Low-side Downconversion, LO = +17 dBm, IF = 70 MHz



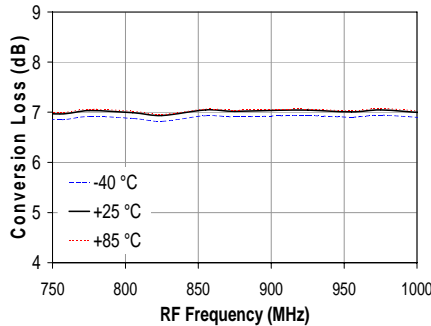
Input IP3 vs RF Frequency vs LO Power
Low-side Downconversion, IF = 70 MHz, 25 °C



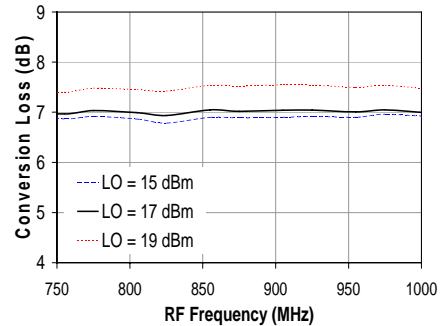
Conv. Loss vs RF Frequency vs IF Frequency
Low-side Downconversion, LO = +17 dBm, 25 °C



Conv. Loss vs RF Frequency vs Temperature
Low-side Downconversion, LO = +17 dBm, IF = 70 MHz

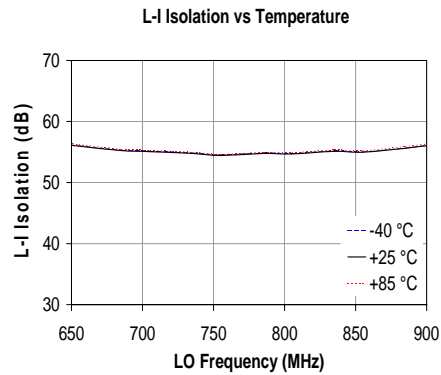
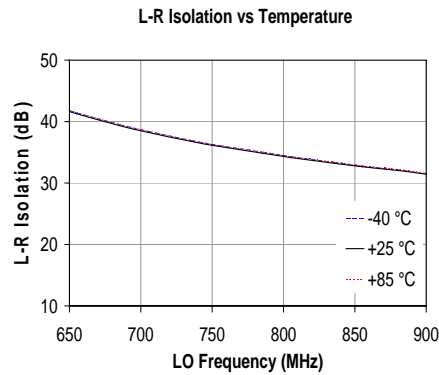
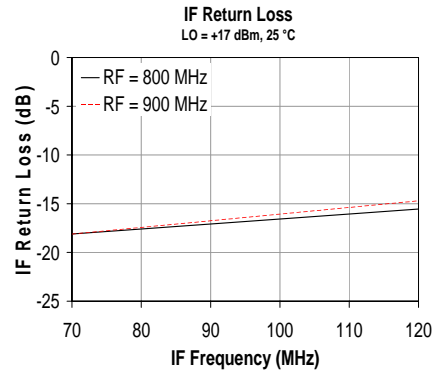
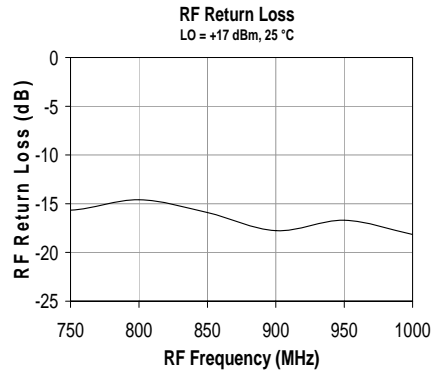
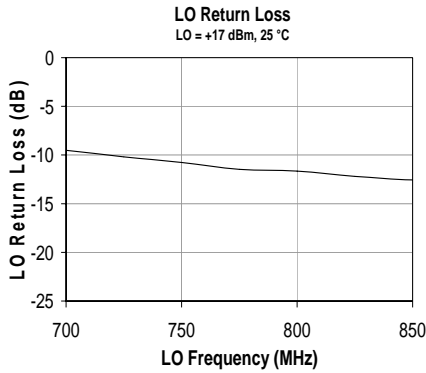


Conv. Loss vs RF Frequency vs LO Power
Low-side Downconversion, IF = 70 MHz, 25 °C





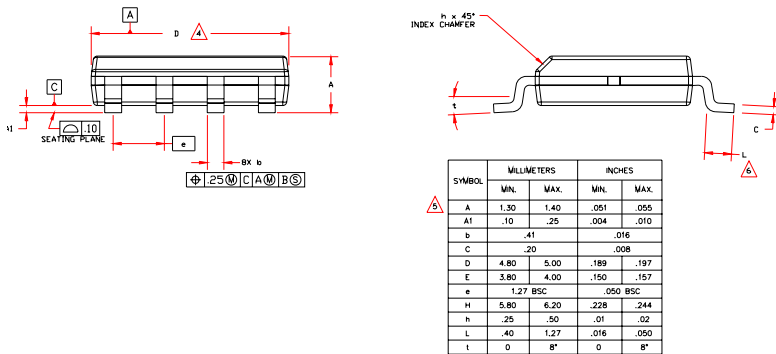
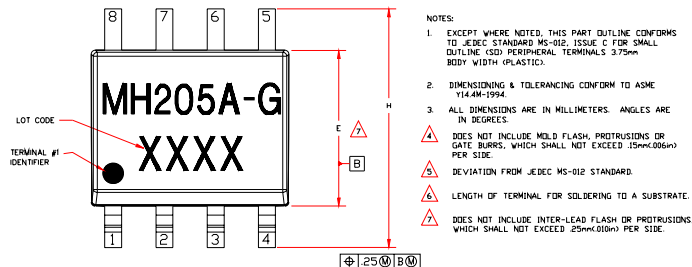
Typical Downconversion Performance Plots (cont'd) Performance using the circuitry on the MH205A-PCB Evaluation Board



MH205A-G (Lead-Free/Green SOIC-8 Package) Mechanical Information

This package is lead-free/green/RoHS-compliant. The plating material on the leads is NiPdAu. It is compatible with both lead-free (maximum 260 °C reflow temperature) and lead (maximum 245 °C reflow temperature) soldering processes.

Outline Drawing



Product Marking

The component will be marked with an "MH205A-G" designator with an alphanumeric lot code on the top surface of the package. The obsolete tin-lead package is marked with an "M205A" designator with an alpha numeric lot code.

Tape and reel specifications for this part are located on the website in the "Application Notes" section.

ESD / MSL Information



Caution! ESD sensitive device.

ESD Rating: Class 1B

Value: Passes ≥ 500V to <1000 V

Test: Human Body Model (HBM)

Standard: JEDEC Standard JESD22-A114

ESD Rating: Class III

Value: Passes ≥ 500 V to <1000 V

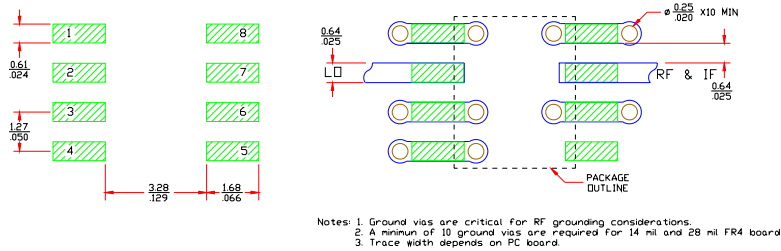
Test: Charged Device Model (CDM)

Standard: JEDEC Standard JESD22-C101

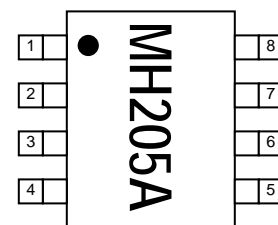
MSL Rating: Level 2 at +260 °C convection reflow

Standard: JEDEC Standard J-STD-020

Land Pattern / Mounting Configuration



Functional Pin Layout



Pin	Function
1	Ground
2	LO Port
3	Ground
4	Ground
5	No Connect / Ground
6	Ground
7	RF / IF Port*
8	Ground

* External components (inductors & capacitors) are required to duplex the signal